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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/944,426	08/30/2001	Vladislav Vashchenko	75292/13356	1844

7590 07/19/2007  
Jurgen K Vollrath  
588 Sutter Street #531  
San Francisco, CA 94102

EXAMINER

NADAV, ORI

ART UNIT	PAPER NUMBER
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2811

MAIL DATE	DELIVERY MODE
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07/19/2007

PAPER

**Please find below and/or attached an Office communication concerning this application or proceeding.**

The time period for reply, if any, is set in the attached communication.

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<b>Office Action Summary</b>	<b>Application No.</b>	<b>Applicant(s)</b>	
	09/944,426	VASHCHENKO, VLADISLAV	
	<b>Examiner</b>	<b>Art Unit</b>	
	Ori Nadav	2811	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

### Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

### Status

- 1) ☒ Responsive to communication(s) filed on 27 April 2007.
- 2a) ☒ This action is **FINAL**. 2b) ☐ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

### Disposition of Claims

- 4) ☒ Claim(s) 1-4 is/are pending in the application.
- 4a) Of the above claim(s) 1 is/are withdrawn from consideration.
- 5) ☐ Claim(s) \_\_\_\_\_ is/are allowed.
- 6) ☒ Claim(s) 2-4 is/are rejected.
- 7) ☐ Claim(s) \_\_\_\_\_ is/are objected to.
- 8) ☐ Claim(s) \_\_\_\_\_ are subject to restriction and/or election requirement.

### Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on \_\_\_\_\_ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.  
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).  
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

### Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some \* c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
  2. ☐ Certified copies of the priority documents have been received in Application No. \_\_\_\_\_.
  3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
- \* See the attached detailed Office action for a list of the certified copies not received.

### Attachment(s)

- |  |   |
|--|---|
| 1) <input type="checkbox"/> Notice of References Cited (PTO-892)   | 4) <input type="checkbox"/> Interview Summary (PTO-413)<br>Paper No(s)/Mail Date. _____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948)                       | 5) <input type="checkbox"/> Notice of Informal Patent Application                       |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO/SB/08)<br>Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____  |

## **DETAILED ACTION**

### ***Claim Rejections - 35 USC § 112***

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claim 2 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention. The claimed limitations of "said p+ region of the defined p-n junction located on the high voltage side of said at least one n+ region of the defined p-n junction", as recited in claim 2, are unclear as to which p+ region is "said p+ region", which n+ region is "said n+ region", whether "the defined p-n junction" is the "p-n junction", and how the p+ region is located on the high voltage side of said at least one n+ region, because the p+ region is located on the low voltage side.

The intended recitation of the claim is unclear to the examiner. However, one possible recitation of the above phrase, which is not indefinite is "a p+ region of the p-n junction is located closer to the high voltage node than an n+ region of the p-n junction".

### ***Claim Rejections - 35 USC § 103***

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

Claims 2-4, as best understood, are rejected under 35 U.S.C. 103(a) as being unpatentable over Ker et al. (6,573,566) in view of Yu (5,361,185).

Regarding claim 2, Ker et al. teach in figure 8B and related text a method of increasing the holding voltage of an LVTSCR structure that includes an n-well 208 and a p-well 206 formed in a substrate 200, an n+ region 214 and a p+ region 212 formed in the n-well to define a high voltage node, the method comprising forming at least one additional p+ region 222 and at least one n+ region 220 inside the p-well of the structure to define at least one p-n junction between the p-type material of the p-well and one of the p+ regions in the p-well on the one hand, and the n-type material of at least one of any one of the n+ regions in the p-well on the other hand, the p-n junction being forward biased during normal operation by having said p+ region of the defined p-n junction located on the high voltage side of said at least one n+ region of the defined p-n junction.

Regarding claims 3-4, Ker et al. teach in figure 8B and related text a method of increasing the holding voltage of an LVTSCR structure having an anode in an n-well and a cathode in a p-well, comprising

forming at least one additional n+ region 220 and at least one additional p+ region 222 in the p-well to define at least one forward biased diode under normal operation in the p-well, thereby providing an alternative current path from anode to cathode through said at least one diode,

wherein the alternative current path defines a lower resistance current path than the p-well.

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Ker et al. do not teach in the embodiment of figure 8B and an n+ region and a p+ region formed in the p-well.

Ker et al. teach in figure 10B a diode 324 connected to the cathode of SCR G2.

Yu teaches in figure 4 and related text a diode comprising an n+ region 50 and a p+ region 56 formed in a p substrate 24.

It would have been obvious to a person of ordinary skill in the art at the time the invention was made to form a diode comprising an n+ region and a p+ region in the p-well in Ker et al.'s device in order to provide protection to the device, and in order to reduce the size of the device and to simplify the processing steps of making the device.

### ***Response to Arguments***

Applicant argues that Yu teaches a diode in reverse bias and under normal operation and not a diode in a forward bias, as required by the claims.

Yu was not cited to teach an artisan the claimed limitations of a forward biased diode. Yu was merely cited to teach an artisan that a diode can be formed in a p region by using an n+ region and a p+ region. Ker teaches a diode in a forward bias under normal cooperation.

Note that the broad recitation of the claim does not require Ker and Yu to have a device comprising a floating drain region.

***Conclusion***

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire **THREE MONTHS** from the mailing date of this action. In the event a first reply is filed within **TWO MONTHS** of the mailing date of this final action and the advisory action is not mailed until after the end of the **THREE-MONTH** shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than **SIX MONTHS** from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Ori Nadav whose telephone number is 571-272-1660. The examiner can normally be reached between the hours of 7 AM to 4 PM (Eastern Standard Time) Monday through Friday.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Lynne Gurley can be reached on 571-272-4670. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).



O.N.  
7/17/07

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